## NSN 5962-01-165-0870

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Maximum Power Dissipation Rating:
220.0 milliwatts
Operating Tempurature Range:
-0.0/+70.0 degrees celsius
End Application:
5895-01-129-1827 communications central
Features Provided:
Static operation and erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Time Rating Per Chacteristic:
300.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Terminal Type And Quantity:
18 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0